

### NPN 6A 30V Middle Power Transistor

Parameter	Value
V <sub>CEO</sub>	30V
I <sub>C</sub>	6A

#### Features

- 1) Suitable for Middle Power Driver
- 2) Low  $V_{CE(sat)}$  $V_{CE(sat)}$ = 180mV(Max.) ( $I_C/I_B$ =3A/60mA)
- 3) High collector current

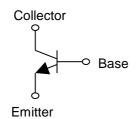
 $I_C = 6A \text{ (max)}, I_{CP} = 7A \text{ (max)}$ 

- 4) Leadless small SMD package "HUML2020L3" Excellent thermal and electrical conductivity
- 5) Lead Free/RoHS Compliant.

### Outline



#### •Inner circuit



### Applications

Load switch, Battery-driven devices, Power management Charging circuits, Power switches (e.g. motors, fans)

### Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SCR562F3	HUML2020L3	2020	TR	180	8	3,000	NT

### ● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Values	Unit
Collector-base voltage		$V_{CBO}$	30	V
Collector-emitter voltage		V <sub>CEO</sub>	30	V
Emitter-base voltage	e voltage V <sub>EBO</sub>		6	V
0.11.4	DC	I <sub>C</sub>	6.0	А
Collector current	Pulsed	I <sub>CP</sub> *1	7.0	А
Base Current		I <sub>B</sub>	0.6	А
Power dissipation		P <sub>D</sub> *2	1.0	W
		P <sub>D</sub> *3	2.1	W
Junction temperature		T <sub>j</sub>	150	°C
Range of storage temperature		T <sub>stg</sub>	−55 to +150	°C

<sup>\*1</sup> Pw=1ms, single pulse

# ●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV <sub>CEO</sub>	I <sub>C</sub> = 1mA	30	-	-	V
Collector-base breakdown voltage	BV <sub>CBO</sub>	I <sub>C</sub> = 100μA	30	ı	ı	V
Emitter-base breakdown voltage	BV <sub>EBO</sub>	I <sub>E</sub> = 100μA	6	-	ı	V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 20V	ı	1	0.5	μА
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 4V	ı	ı	0.5	μА
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{\rm C} = 3A, I_{\rm B} = 60 \text{mA}$	1	120	180	mV
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_{C} = 3A, I_{B} = 60 \text{mA}$	ı	0.9	1.2	V
DC current gain	h <sub>FE</sub>	$V_{CE} = 2V, I_{C} = 500 \text{mA}$	200	-	500	-
Transition frequency	f⊤	$V_{CE} = 10V, I_{E} = -500 \text{mA}$ f=100MH <sub>Z</sub>	ı	270	ı	MHz
Output capacitance	C <sub>ob</sub>	$V_{CB} = 10V$ , $I_E = 0A$ f = 1MHz	-	40	-	pF

<sup>\*2</sup> Mounted on an FR4 board (25.4×25.4×1.6mm, 645mm<sup>2</sup> Cu PAD)

<sup>\*3</sup> Pw=10s, Mounted on an FR4 board (25.4×25.4×1.6mm, 645mm<sup>2</sup> Cu PAD)

### ●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

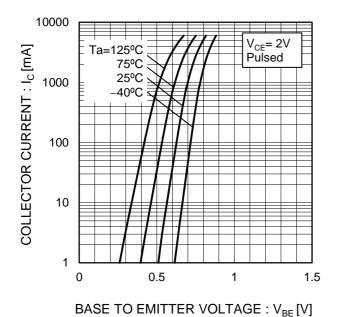
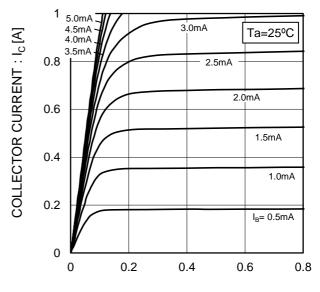


Fig.2 Typical Output Characteristics



COLECTOR TO EMITTE VOLTAGE: V<sub>CE</sub>[V]

Fig.3 DC Current Gain vs. Collector Current(I)

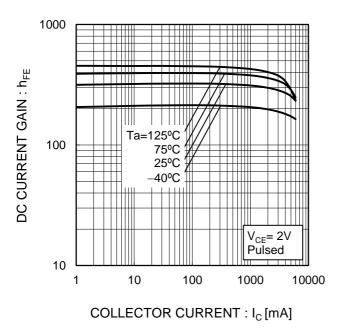
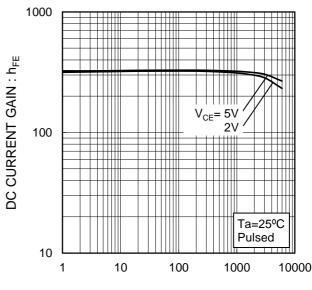
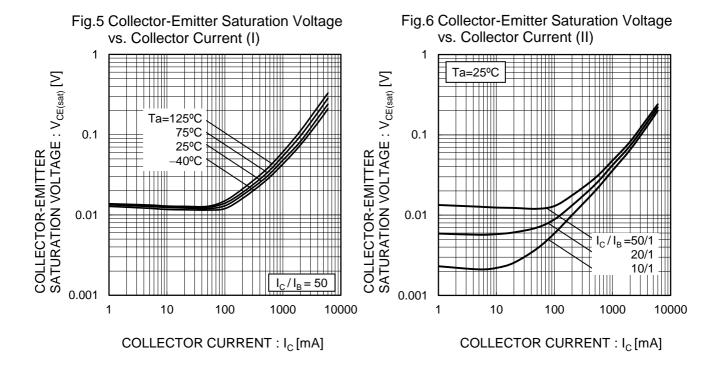


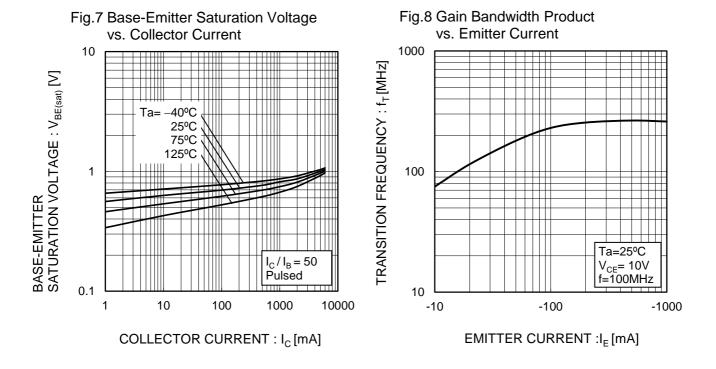
Fig.4 DC Current Gain vs. Collector Current(II)



COLLECTOR CURRENT :  $I_C$  [mA]

### ●Electrical characteristic curves(Ta = 25°C)





## ●Electrical characteristic curves(Ta = 25°C)

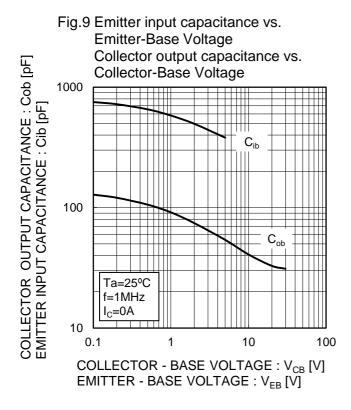
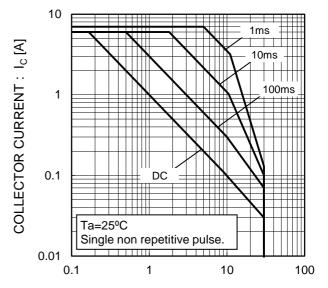
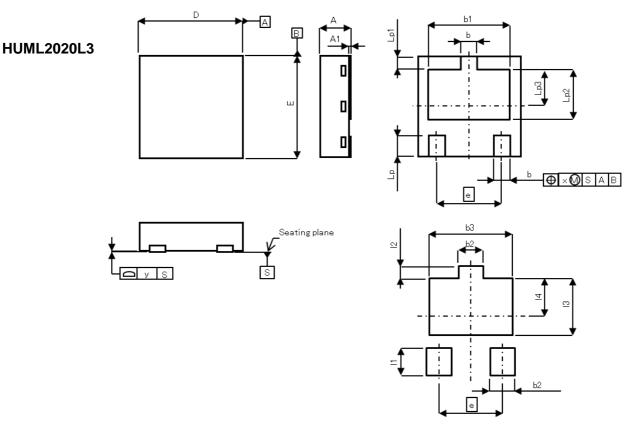


Fig.10 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE :  $V_{CE}\left[V\right]$ 

# ●Dimensions (Unit:mm)



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIME	TERS INCHE		HES		
DIIVI	MIN	MAX	MIN	MAX		
Α	0.55	0.65	0.022	0.026		
A1	0.00	0.05	0.000	0.002		
b	0.25	0.35	0.010	0.014		
b1	1.40	1.60	0.055	0.063		
D	1.90	2.10	0.075	0.083		
E	1.90	2.10	0.075	0.083		
е	1.3	1.30		0.051		
Lp	0.35	0.45	0.014	0.018		
Lp1	0.25	REF	0.01	REF		
Lp2	0.90	1.10	0.035	0.043		
Lp3	0.70	0.80	0.028	0.031		
Х	-	0.10	-	0.004		
у	-	0.10	-	0.004		

DIM	MILIME	TERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
b2	-	0.45	-	0.018	
b3	-	1.60	-	0.063	
l1	-	0.55	-	0.022	
12	0.25	REF	0.01	REF	
13	-	1.10	-	0.043	
14	-	0.80	-	0.031	

Dimension in mm / inches

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